

# STM809, STM810 STM811, STM812

### **Reset circuit**

### Features

- Precision monitoring of 3 V, 3.3 V, and 5 V supply voltages
- Two output configurations
  - Push-pull RST output (STM809/811)
  - Push-pull RST output (STM810/812)
- 140 ms reset pulse width (min)
- Low supply current 6 µA (typ)
- Guaranteed RST/RST assertion down to V<sub>CC</sub> = 1.0 V
- Operating temperature:
   -40 °C to 85 °C (industrial grade)
- Lead-free, small SOT23 and SOT143 package



	Active-low reset	Active-high reset	Manual reset input	Package
STM809	~			SOT23-3
STM810		~		SOT23-3
STM811	~		~	SOT143-4
STM812		~	~	SOT143-4

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## 1 Description

The STM809/810/811/812 microprocessor reset circuits are low-power supervisory devices used to monitor power supplies. They perform a single function: asserting a reset signal whenever the V<sub>CC</sub> supply voltage drops below a preset value and keeping it asserted until V<sub>CC</sub> has risen above the preset threshold for a minimum period of time (t<sub>rec</sub>). The STM811/812 also provide a push-button reset input ( $\overline{MR}$ ).





1. For STM810





1. For STM812

Table 2.	Signal names
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V <sub>SS</sub>	Ground
RST	Active-low reset output
RST <sup>(1)</sup>	Active-high reset output
V <sub>CC</sub>	Supply voltage
MR <sup>(2)</sup>	Manual reset input

1. STM810/812 only

2. STM811/812 only







#### Figure 4. SOT143-4 connections



#### Figure 5. Block diagram



1. STM811/812 only

2. RST for STM810/812





1. STM809/811 only (RST for STM810/812)

2. STM811/812 only



### 2 Operation

#### 2.1 Reset output

The STM809/810/811/812 microprocessor reset circuit asserts a reset signal to the MCU whenever V<sub>CC</sub> goes below the reset threshold (V<sub>RST</sub>), or when the push-button reset input ( $\overline{\text{MR}}$ ) is taken low (see *Figure 14 on page 13*). RST (active high for STM810/812) is guaranteed valid down to V<sub>CC</sub> = 1 V (0° to 70°C).

During power-up, once  $V_{CC}$  exceeds the reset threshold an internal timer keeps  $\overline{RST}$  low for the reset time-out period, t<sub>rec</sub>. After this interval,  $\overline{RST}$  returns high.

If  $V_{CC}$  drops below the reset threshold,  $\overline{RST}$  goes low. Each time  $\overline{RST}$  is asserted, it stays low for at least the reset time-out period. Any time  $V_{CC}$  goes below the reset threshold, the internal timer clears. The reset timer starts when  $V_{CC}$  returns above the reset threshold. The active-low reset ( $\overline{RST}$ ) and active-high reset (RST) both source and sink current.

### 2.2 Push-button reset input (STM811/812)

A logic low on  $\overline{\text{MR}}$  asserts  $\overline{\text{RST}}$ .  $\overline{\text{RST}}$  remains asserted while  $\overline{\text{MR}}$  is low, and for  $t_{\text{rec}}$  after it returns high. The  $\overline{\text{MR}}$  input has an internal 20 k $\Omega$  pull-up resistor, allowing it to be left open if not used. This input can be driven with TTL/CMOS-logic levels or with open-drain/collector outputs. Connect a normally open push-button switch from  $\overline{\text{MR}}$  to GND to create a manual reset function; external debounce circuitry is not required. If the device is used in a noisy environment, connect a 0.1  $\mu$ F capacitor from  $\overline{\text{MR}}$  to GND to provide additional noise immunity.

### 2.3 Negative-going V<sub>CC</sub> transients

The STM809/810/811/812 are relatively immune to negative-going V<sub>CC</sub> transients (glitches). *Figure 12 on page 11* shows typical transient duration versus reset comparator overdrive (for which the STM809/810/811/812 will NOT generate a reset pulse). The graph was generated using a negative pulse applied to V<sub>CC</sub>, starting at 0.5V above the actual reset threshold and ending below it by the magnitude indicated (comparator overdrive). The graph indicates the maximum pulse width a negative V<sub>CC</sub> transient can have without causing a reset pulse. As the magnitude of the transient increases (further below the threshold), the maximum allowable pulse width decreases. Any combination of duration and overdrive which lies under the curve will NOT generate a reset signal. Typically, a V<sub>CC</sub> transient that goes 100 mV below the reset threshold and lasts 20 µs or less will not cause a reset pulse. A 0.1 µF bypass capacitor mounted as close as possible to the V<sub>CC</sub> pin provides additional transient immunity.



# 2.4 Valid $\overline{\text{RST}}$ output down to V<sub>CC</sub> = 0 V

When V<sub>CC</sub> falls below 1 V, the  $\overline{\text{RST}}$  (STM809/811) output no longer sinks current, but becomes an open circuit. In most systems this is not a problem, as most MCUs do not operate below 1 V. However, in applications where  $\overline{\text{RST}}$  output must be valid down to 0 V, a pull-down resistor may be added to hold the  $\overline{\text{RST}}$  output low. This resistor must be large enough to not load the  $\overline{\text{RST}}$  output, and still be small enough to pull the output to ground. A 100 k $\Omega$  resistor is recommended.

Note: The same situation applies for the active-high RST of the STM810/812. A 100 k $\Omega$  pull-up resistor to V<sub>CC</sub> should be used if RST must remain valid for V<sub>CC</sub> < 1.0 V.



# **3** Typical operating characteristics

Note: Typical values are at  $T_A = 25$  °C,  $V_{CC} = 5$  V for L/M versions,  $V_{CC} = 3.3$  V for T/S versions, and  $V_{CC} = 3.0$  V for R versions.



Figure 7. Supply current vs. temperature, L/M/R/S/T (no load)









Figure 9. Power-down reset delay vs. temperature -  $V_{OD} = V_{TH} - V_{CC}$  (R/S/T)









Figure 11. Normalized reset threshold vs. temperature







## 4 Maximum ratings

Stressing the device above the rating listed in the absolute maximum ratings table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Symbol	Parameter	Value	Unit
T <sub>STG</sub>	Storage temperature (V <sub>CC</sub> off)	-55 to 150	°C
T <sub>SLD</sub> <sup>(1)</sup>	Lead solder temperature for 10 seconds	260	°C
V <sub>IO</sub>	Input or output voltage	–0.3 to V <sub>CC</sub> +0.3	V
V <sub>CC</sub>	Supply voltage	-0.3 to 7.0	V
Ι <sub>Ο</sub>	Output current	20	mA
PD	Power dissipation	320	mW

 Table 3.
 Absolute maximum ratings

1. Reflow at peak temperature of 260 °C. The time above 255 °C must not exceed 30 seconds.





## 5 DC and AC parameters

This section summarizes the operating measurement conditions, and the DC and AC characteristics of the device. The parameters in the DC and AC characteristics tables that follow, are derived from tests performed under the measurement conditions summarized in *Table 4.*. Designers should check that the operating conditions in their circuit match the operating conditions when relying on the quoted parameters.

Table 4.	Operating and AC measurement conditions
----------	---

Parameter	STM809/810/811/812	Unit
V <sub>CC</sub> supply voltage	1.0 to 5.5	V
Ambient operating temperature (T <sub>A</sub> )	-40 to 85	°C
Input rise and fall times	≤ 5	ns
Input pulse voltages	0.2 to 0.8 V <sub>CC</sub>	V
Input and output timing ref. voltages	0.3 to 0.7 V <sub>CC</sub>	V

#### Figure 13. AC testing input/output waveforms



#### Figure 14. MR timing waveform



1. RST for STM810/812



Sym	Alter- native	Description	Test con	dition <sup>(1)</sup>	Min	Тур	Мах	Unit
V <sub>CC</sub>		Operating voltage	$T_{A} = -40 \text{ t}$	o +85 °C	1.2		5.5	V
VCC ▼		Operating voltage	$T_A = 0$ to		1.0		5.5	V
I <sub>CC</sub>		V <sub>CC</sub> supply current	V <sub>CC</sub> < 3.6 V			5.5	10	μA
'CC		ACC subbly content	V <sub>CC</sub> <			7	15	μA
VIH		MR input high voltage	V <sub>CC</sub> > V <sub>RST</sub> (max		2.2			V
• IH		in thip at high voltage			0.7 V <sub>CC</sub>			V
VIL		MR input low voltage	$V_{CC} > V_{RST}$ (max				0.8	V
۶IL			$V_{CC} > V_{RST}$ (max)				0.25 V <sub>CC</sub>	V
			STM8XXR					
			I <sub>OL</sub> = 1				0.3	V
V <sub>OL</sub>		RST output low voltage (active high <sup>(2)</sup> or low)	$V_{CC} = V_{R}$					
			STM8XXI				0.4	v
			I <sub>OL</sub> = 3.2 mA V <sub>CC</sub> = V <sub>RST</sub> (min)				0.4	v
V <sub>OL</sub>		RST output low voltage	I <sub>OL</sub> = 50 μA;				0.3	V
ΟL		RST output high voltage	STM8XXR		0.8 V <sub>CC</sub>			
				$I_{OH} = 500 \ \mu A$				V
V.			STM8XXL/M only, I <sub>OH</sub> = 800 μA		0.8 V <sub>CC</sub>			v
V <sub>OH</sub>								v
		RST output high voltage	I <sub>OH</sub> = 150 μA,		0.8 V <sub>CC</sub>			v
			1.8 V < V <sub>CC</sub> < V <sub>RST</sub> (min)					
Reset	threshol	ds						
			STMOVVI	25 °C	4.56	4.63	4.70	V
			STM8XXL	–40 to 85 °C	4.50		4.75	V
			STM8XXM	25 °C	4.31	4.38	4.45	V
			OTWOXXW	–40 to 85 °C	4.25		4.50	V
V <sub>RST</sub>		Reset threshold	STM8XXT	25 °C	3.04	3.08	3.11	V
VRS1		Tieset threshold	OTWOXXT	–40 to 85 °C	3.00		3.15	V
			STM8XXS	25 °C	2.89	2.93	2.96	V
				–40 to 85 °C	2.85		3.00	V
			STM8XXR	25 °C	2.59	2.63	2.66	V
			CTWOXXII	–40 to 85 °C	2.55		2.70	V
		V <sub>RST</sub> temperature coefficient	V <sub>CC</sub> =	V <sub>CC</sub> = 3.3 V		45		ppm/ °C
		$V_{CC}$ to $\overline{RST}$ delay	$V_{CC} = V_{RST}$ to	STM8XXL/M		40		μs
		VCC IO NOT UEIAY	(V <sub>RST</sub> – 100 mV)	STM8XXR/S/T		20		μs

 Table 5.
 DC and AC characteristics



Sym	Alter- native	Description	Test condition <sup>(1)</sup>	Min	Тур	Мах	Unit	
Push-b	Push-button reset input							
t <sub>MLMH</sub>	t <sub>MR</sub>	MR pulse width		10			μs	
t <sub>MLRL</sub>	t <sub>MRD</sub>	MR to RST output delay <sup>(3)</sup>			0.5		μs	
		MR glitch immunity <sup>(4)</sup>			100		ns	
		MR pull-up resistance		10	20	30	kΩ	
	t <sub>rec</sub>	RST pulse width		140	210	280	ms	

1. Valid for ambient operating temperature:  $T_A = -40$  to 85 °C;  $V_{CC} = 1.2$  V to 5.5 V (except where noted).

2. For active high (RST);  $V_{CC} = V_{RST}$  (max)

3. RST output for STM810/812

4. "Glitches" of 100 ns or less typically will not generate a reset pulse.



## 6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.





Note:

Drawing is not to scale.

Symbol	mm			inches		
	Тур	Min	Max	Тур	Min	Мах
А		0.89	1.12		0.035	0.044
A1		0.01	0.10		0.001	0.004
A2		0.88	1.02		0.035	0.042
b		0.30	0.50		0.012	0.020
С		0.08	0.20		0.003	0.008
D		2.80	3.04		0.110	0.120
Е		2.10	2.64		0.083	0.104
E1		1.20	1.40		0.047	0.055
е		0.89	1.03		0.035	0.041
e1		1.78	2.05		0.070	0.081
L	0.54			0.021		
L1		0.40	0.60		0.016	0.024
Θ		0°	8°		0°	8°
Ν		3			3	•

Table 6.	SOT23-3 – 3-lead small outline transistor package mechanical data
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Figure 16. SOT143-4 – 4-lead small outline transistor package outline

Note:

Drawing is not to scale.

 Table 7.
 SOT143-4 – 4-lead small outline transistor package mechanical data

Symbol	mm			inches		
	Тур	Min	Max	Тур	Min	Мах
А		0.89	1.12		0.035	0.044
A1		0.01	0.10		0.001	0.004
A2		0.88	1.02		0.035	0.042
b		0.37	0.51		0.015	0.020
b2		0.76	0.94		0.030	0.037
С		0.09	0.18		0.004	0.007
D		2.80	3.04		0.110	0.120
Е		2.10	2.64		0.083	0.104
E1		1.20	1.40		0.047	0.055
е	1.92			0.076		
e1	0.20			0.008		
L	0.55			0.022		
L1		0.40	0.60		0.016	0.024
Θ		0°	10°		0°	10°
Ν		4			4	

# 7 Part numbering

Table 8. Ordering information	scheme				
Example:	STM8XX	L	WX	6	I
Device type					
STM8XX					
Reset threshold voltage					
$L = V_{RST} = 4.50 \text{ V to } 4.75 \text{ V}$					
$M = V_{RST} = 4.25 V \text{ to } 4.50 V$					
T = V <sub>RST</sub> = 3.00 V to 3.15 V					
S = V <sub>RST</sub> = 2.85 V to 3.00 V					
$R = V_{RST} = 2.55 V \text{ to } 2.70 V$					
Package					
WX = SOT23-3 (STM809, STM810)					
W1 = SOT143-4 (STM811, STM812)					
Temperature range					
6 = −40 to 85 °C					
Shipping method					
F = ECOPACK <sup>®</sup> package, tape & reel					

For a list of available options (e.g., speed, package) or for further information on any aspect of this device, please contact the ST sales office nearest to you.



Part number	Reset threshold	Output	Topside marking <sup>(1)</sup>
STM809L	4.63 V	Push-pull RST	8AAx
STM809M	4.38 V	Push-pull RST	8ABx
STM809T	3.08 V	Push-pull RST	8ACx
STM809S	2.93 V	Push-pull RST	8ADx
STM809R	2.63 V	Push-pull RST	8AEx
STM810L	4.63 V	Push-pull RST	8AFx
STM810M	4.38 V	Push-pull RST	8AGx
STM810T	3.08 V	Push-pull RST	8AHx
STM810S	2.93 V	Push-pull RST	8AJx
STM810R	2.63 V	Push-pull RST	8AKx
STM811L	4.63 V	Push-pull RST	8ALx
STM811M	4.38 V	Push-pull RST	8AMx
STM811T	3.08 V	Push-pull RST	8ANx
STM811S	2.93 V	Push-pull RST	8APx
STM811R	2.63 V	Push-pull RST	8AQx
STM812L	4.63 V	Push-pull RST	8ARx
STM812M	4.38 V	Push-pull RST	8ASx
STM812T	3.08 V	Push-pull RST	8ATx
STM812S	2.93 V	Push-pull RST	8AUx
STM812R	2.63 V	Push-pull RST	8AVx

Table 9. Marking description

1. x = letter assigned to indicate assembly work week (i.e., A = WW01 and WW02, B = WW03 and WW04, C = WW05 and WW06..., Z = WW51, WW52, and WW53).



# 8 Revision history

Table 10.	Document	revision	history
			· · · · <b>,</b>

Date	Revision	Changes		
02-Sep-2003	1	First issue		
03-Oct-2003	1.1	Update operating characteristics ( <i>Figure 7</i> , <i>Figure 8</i> , <i>Figure 9</i> , <i>Figure 10</i> , <i>Figure 11</i> , <i>Figure 12</i> )		
16-Oct-2003	1.2	Update characteristics (Table 5); modify illustration (Figure 12)		
17-Nov-2003	1.3	Modified with JEDEC timing symbols ( <i>Figure 14</i> ; <i>Table 5</i> )		
04-Dec-2003	2	Reformatted; promoted; updated (Figure 14; Table 5, 6)		
09-Dec-2003	2.1	Correct timing label, combine characteristics (Figure 10; Table 5)		
10-Feb-2004	3	Clarify package; update DC characteristics (Table 5, Table 8)		
19-Nov-2004	4	Update dimensions (Table 6).		
05-Jan-2010	5	Updated footnote in <i>Table 3</i> , added text to <i>Section 6: Package mechanical data</i> , added footnote to <i>Table 9</i> .		



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